

International IOR Rectifier

30WQ10FN

SCHOTTKY RECTIFIER

3.5 Amp



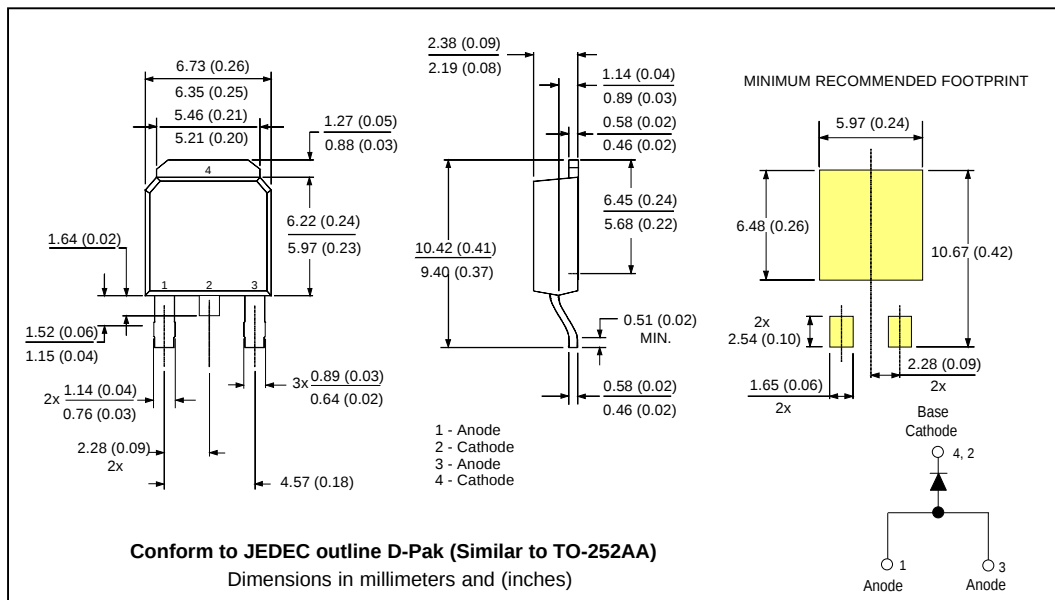
Major Ratings and Characteristics

Characteristics	30WQ10FN	Units
$I_{F(AV)}$ Rectangular waveform	3.5	A
V_{RRM}	100	V
I_{FSM} @ $t_p = 5 \mu s$ sine	440	A
V_F @ 3 Apk, $T_J = 125^\circ C$	0.63	V
T_J	-40 to 150	$^\circ C$

Description/ Features

The 30WQ10FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	30WQ10FN
V_R Max. DC Reverse Voltage (V)	100
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	30WQ...	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	3.5	A	50% duty cycle @ $T_C = 135^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	440	A	5 μs Sine or 3 μs Rect. pulse
	70		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	5.0	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1\text{ Amp}$, $L = 10\text{ mH}$
I_{AR} Repetitive Avalanche Current	0.5	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	30WQ...	Units	Conditions
V_{FM} Max. Forward Voltage Drop * See Fig. 1 (1)	0.81	V	@ 3A
	0.96	V	@ 6A
	0.63	V	@ 3A
	0.74	V	@ 6A
I_{RM} Max. Reverse Leakage Current * See Fig. 2 (1)	1	mA	$T_J = 25^\circ\text{C}$
	4.9	mA	$T_J = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold Voltage	0.48	V	$T_J = T_J \text{ max.}$
r_t Forward Slope Resistance	30.89	m Ω	
C_T Typical Junction Capacitance	92	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	5.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	30WQ...	Units	Conditions
T_J Max. Junction Temperature Range(*)	-40 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 150	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	4.7	$^\circ\text{C/W}$	DC operation * See Fig. 4
wt Approximate Weight	0.3 (0.01)	g (oz.)	
Case Style	D - PAK		Similar to TO-252AA

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

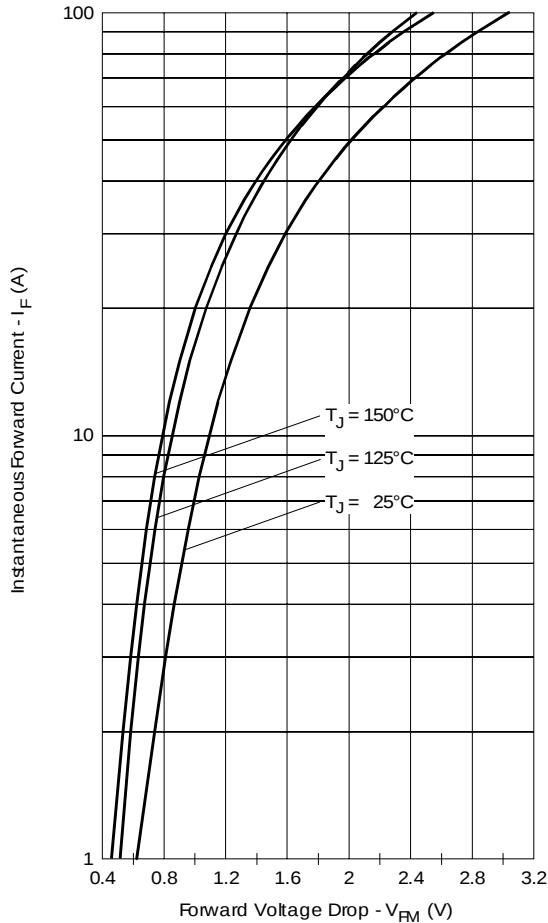


Fig. 1 - Maximum Forward Voltage Drop Characteristics

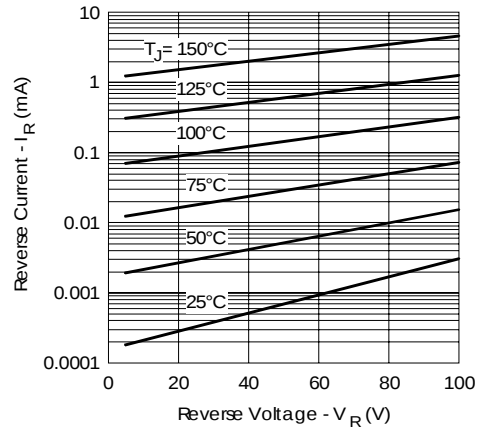


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

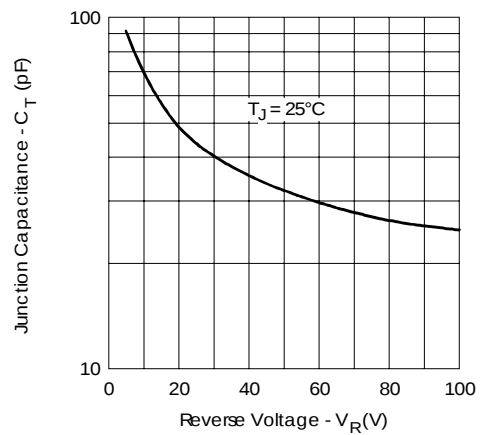


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

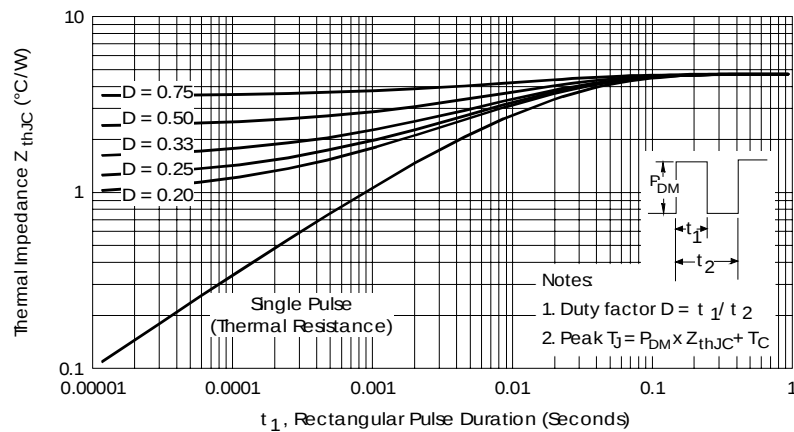


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

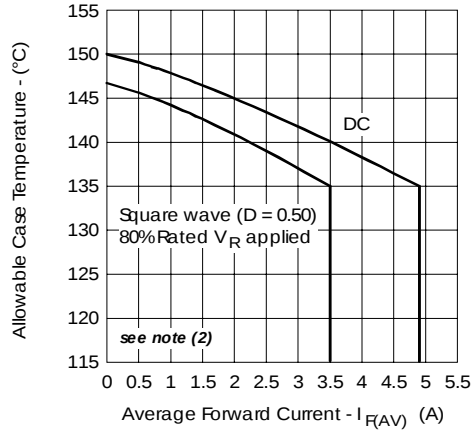


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

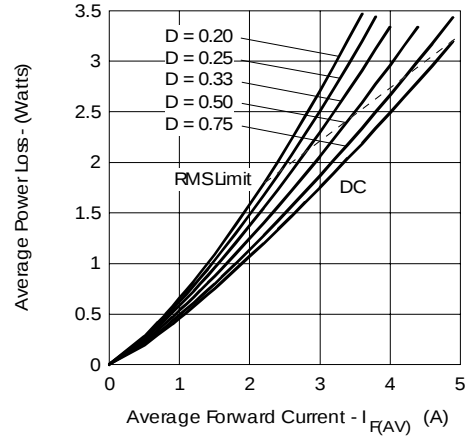


Fig. 6 - Forward Power Loss Characteristics

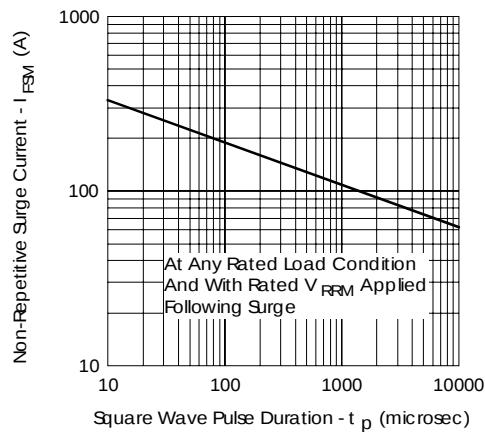


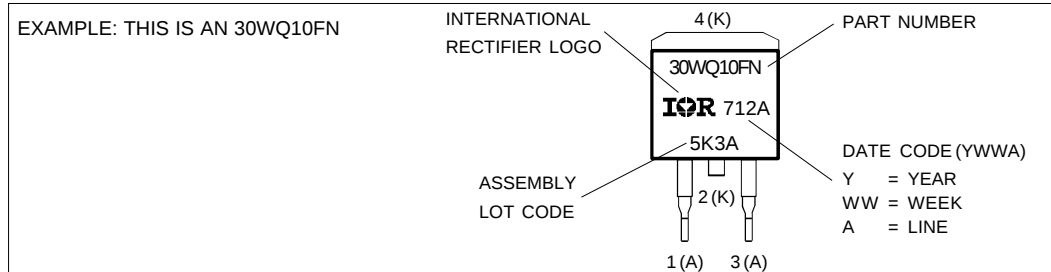
Fig. 7 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

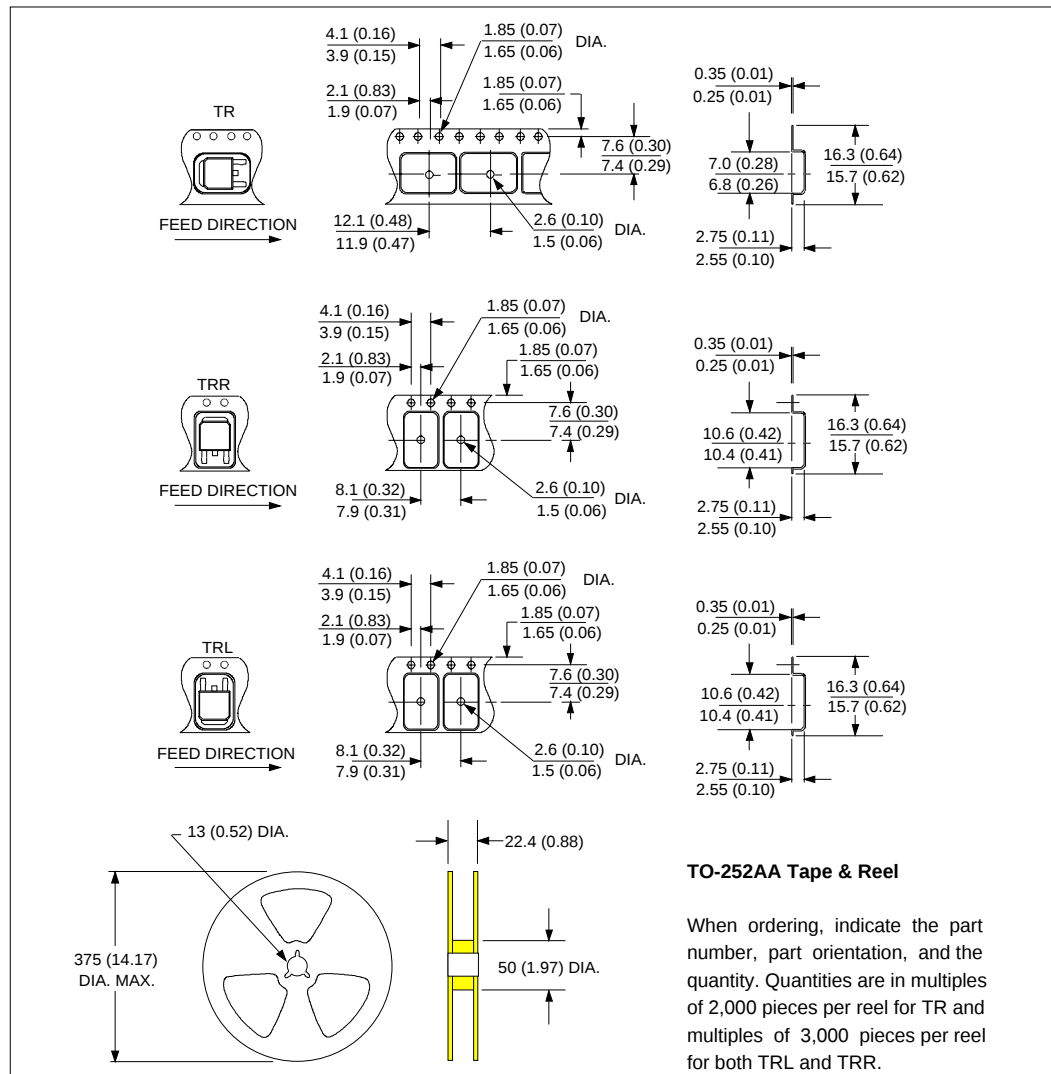
P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Marking Information



Tape & Reel Information



30WQ10FN

Bulletin PD-20523 rev. E 03/03

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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